

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S61	0	S36 and S42	US-PGPU B; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 18:50
S60	4	S53 S58	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 18:49
S59	0	S43 and S44	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 18:48
S54	34	S43 and S44 (S45 S46)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 18:48
S58	2	S43 and S45	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 18:47
S57	0	S43 and S46	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 18:47
S56	37	S43 and S46 (S44 S45)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 18:47

S55	13	S43 and S45 (S44 S46)	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:47
S53	4	S49 S50 S51	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:46
S51	4	S45 and (S43 S44 S46)	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:46
S50	2	S44 and (S43 S45 S46)	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:46
S49	2	S43 and (S44 S45 S46)	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:46
S52	0	S46 and (S43 S44 S45)	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:45
S48	57	S43 S44 S45 S46	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:44
S47	0	S43 and S44 and S45 and S46	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:44

S46	3	S42 and ((essentially consists pure) near (O2 "O.sub.2" "O2" "O.sub.2" O3 "O.sub.3" "O3" "O.sub.3" oxygen ozone))	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:44
S45	31	S42 and (low adj (k dielectric) "low-k" low-k)	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:43
S44	8	S42 and bias\$3	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:43
S43	19	S42 and RF	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:43
S39	129	S38 and (low adj (k dielectric) "low-k" low-k)	US-PGPU B; USPAT	OR	ON	2005/09/13 18:43
S42	700	(resist photoresist) with ash\$3 with (O2 "O.sub.2" "O2" "O.sub.2" O3 "O.sub.3" "O3" "O.sub.3" oxygen ozone)	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:42
S36	3796	(resist photoresist) with ash\$3 with (O2 "O.sub.2" "O2" "O.sub.2" O3 "O.sub.3" "O3" "O.sub.3" oxygen ozone)	US-PGPU B; USPAT	OR	ON	2005/09/13 18:42
S41	18	S38 and ((essentially consists pure) near (O2 "O.sub.2" "O2" "O.sub.2" O3 "O.sub.3" "O3" "O.sub.3" oxygen ozone)) not S40	US-PGPU B; USPAT	OR	ON	2005/09/13 18:35

S40	11	S39 and ((essentially consists pure) near (O2 "O.sub.2" "02" "O.sub.2" O3 "O.sub.3" "03" "O.sub.3" oxygen ozone))	US-PGPU B; USPAT	OR	ON	2005/09/13 18:35
S38	377	S37 and bias\$3	US-PGPU B; USPAT	OR	ON	2005/09/13 18:22
S14	12	((resist photoresist) with (ash\$3 (plasma near strip\$4)) and (RF with (bias\$3 and (plasma source))) ) and (increas\$3 chang\$3 degrad\$3 reduc\$3 decreas\$3 damag\$3 destroy\$3) same (low adj (k dielectric) "low-k" low-k) same (ash\$3 resist photoresist)	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/13 18:22
S37	929	S36 and RF	US-PGPU B; USPAT	OR	ON	2005/09/13 18:21
S35	10	ash\$3 same (source plasma ratio) near power and ("1000" adj (w watt)) and bias\$3	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2003/12/09 12:54
S34	17	ash\$3 same (source plasma ratio) near power and ("1000" adj (w watt))	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2003/12/09 12:53
S33	52	(ash\$3 same (source plasma ratio) near3 power) and ("1000" adj (W watt))	USPAT	OR	OFF	2003/12/09 12:42

S32	149	(ash\$3 same (source plasma ratio) near3 power) and ("1000")	USPAT	OR	OFF	2003/12/09 12:42
S31	584	ash\$3 same (source plasma ratio) near3 power	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2003/12/09 12:42
S29	155	ash\$3 with (source plasma) near power	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2003/12/09 12:41
S30	12	(ash\$3 with bias adj power) and (ash\$3 with (source plasma) near power)	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2003/12/09 12:34
S28	20	ash\$3 with bias adj power	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2003/12/09 12:34
S27	14	((dielectric adj constant with (modify change alter increase decrease) same (ash\$3 strip\$4 plasma)) and bias) and (bias power source) with ratio	USPAT	OR	OFF	2003/12/09 03:50

S26	85	(dielectric adj constant with (modify change alter increase decrease) same (ash\$3 strip\$4 plasma)) and bias	USPAT	OR	OFF	2003/12/09 03:49
S25	324	dielectric adj constant with (modify change alter increase decrease) same (ash\$3 strip\$4 plasma)	USPAT	OR	OFF	2003/12/09 03:49
S24	5277	dielectric adj constant with (modify change alter increase decrease)	USPAT	OR	OFF	2003/12/09 03:48
S23	3	((((US-6455232-\$ or US-6203657-\$ or US-6043164-\$ or US-5272417-\$ or US-6497783-\$ or US-6440864-\$ or US-5981899-\$ or US-6376388-\$ or US-6156629-\$ or US-6500357-\$ or US-6465352-\$ or US-6346490-\$ or US-6342448-\$ or US-6346489-\$ or US-6204192-\$).did. or (US-20030059720-\$ or US-20020084034-\$).did.) and source adj power) and (W watt)	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	OFF	2003/12/09 03:36

S20	6	((US-6455232-\$ or US-6203657-\$ or US-6043164-\$ or US-5272417-\$ or US-6497783-\$ or US-6440864-\$ or US-5981899-\$ or US-6376388-\$ or US-6156629-\$ or US-6500357-\$ or US-6465352-\$ or US-6346490-\$ or US-6342448-\$ or US-6346489-\$ or US-6204192-\$).did. or (US-20030059720-\$ or US-20020084034-\$).did.) and source adj power	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	OFF	2003/12/09 03:36
S22	0	((US-6455232-\$ or US-6203657-\$ or US-6043164-\$ or US-5272417-\$ or US-6497783-\$ or US-6440864-\$ or US-5981899-\$ or US-6376388-\$ or US-6156629-\$ or US-6500357-\$ or US-6465352-\$ or US-6346490-\$ or US-6342448-\$ or US-6346489-\$ or US-6204192-\$).did. or (US-20030059720-\$ or US-20020084034-\$).did.) and source adj power near ("100" "200" "300" "400" "500" "600" "700" "800" "900" "1000")	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	OFF	2003/12/09 03:35

S21	0	((US-6455232-\$ or US-6203657-\$ or US-6043164-\$ or US-5272417-\$ or US-6497783-\$ or US-6440864-\$ or US-5981899-\$ or US-6376388-\$ or US-6156629-\$ or US-6500357-\$ or US-6465352-\$ or US-6346490-\$ or US-6342448-\$ or US-6346489-\$ or US-6204192-\$).did. or (US-20030059720-\$ or US-20020084034-\$).did.) and source adj power near "1000"	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	OFF	2003/12/09 03:35
S19	17	(US-6455232-\$ or US-6203657-\$ or US-6043164-\$ or US-5272417-\$ or US-6497783-\$ or US-6440864-\$ or US-5981899-\$ or US-6376388-\$ or US-6156629-\$ or US-6500357-\$ or US-6465352-\$ or US-6346490-\$ or US-6342448-\$ or US-6346489-\$ or US-6204192-\$).did. or (US-20030059720-\$ or US-20020084034-\$).did.	US-PGPU B; USPAT	OR	OFF	2003/12/09 03:31
S18	5	((resist photoresist) adj (ash\$3 strip\$4) with bias\$3) not (((resist photoresist) adj (ash\$3 strip\$4) with bias\$3) and (RF radio))	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2003/06/22 10:40



S17	15	((resist photoresist) adj (ash\$3 strip\$4) with bias\$3) and (RF radio)	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2003/06/22 10:40
S16	20	(resist photoresist) adj (ash\$3 strip\$4) with bias\$3	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2003/06/22 08:42
S15	141	(resist photoresist) near (ash\$3 strip\$4) same bias\$3	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2003/06/22 08:41